

TOSHIBA Transistor Silicon PNP Epitaxial (PCT process)

# 2SA1298

Low Frequency Power Amplifier Application  
Power Switching Applications

- High DC current gain:  $h_{FE} = 100\sim 320$
- Low saturation voltage:  $V_{CE(sat)} = -0.4\text{ V (max)}$   
( $I_C = -500\text{ mA}$ ,  $I_B = -20\text{ mA}$ )
- Suitable for driver stage of small motor
- Complementary to 2SC3265
- Small package

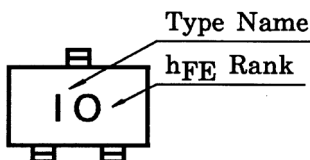
### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-30	V
Collector-emitter voltage	$V_{CEO}$	-25	V
Emitter-base voltage	$V_{EBO}$	-5	V
Collector current	$I_C$	-800	mA
Base current	$I_B$	-160	mA
Collector power dissipation	$P_C$	200	mW
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55~150	$^\circ\text{C}$

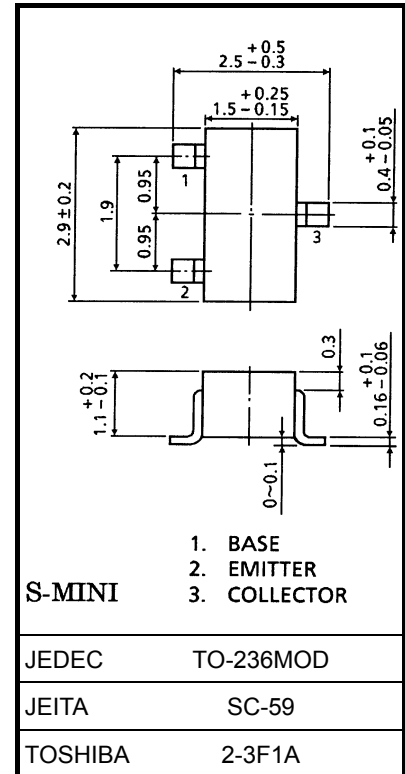
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### Marking



Unit: mm

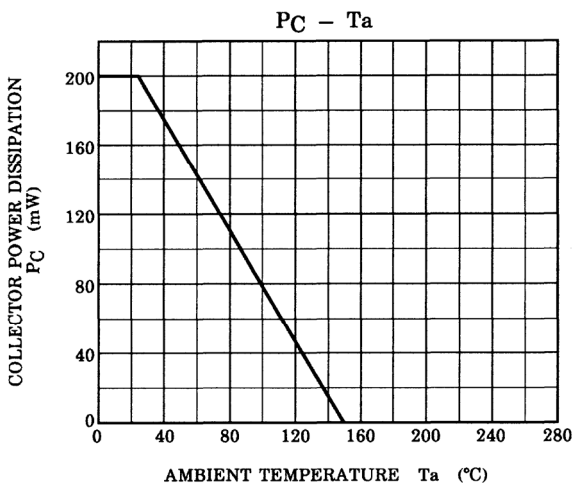
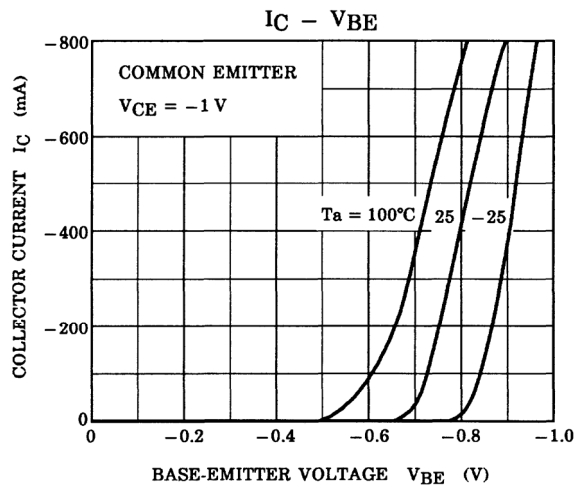
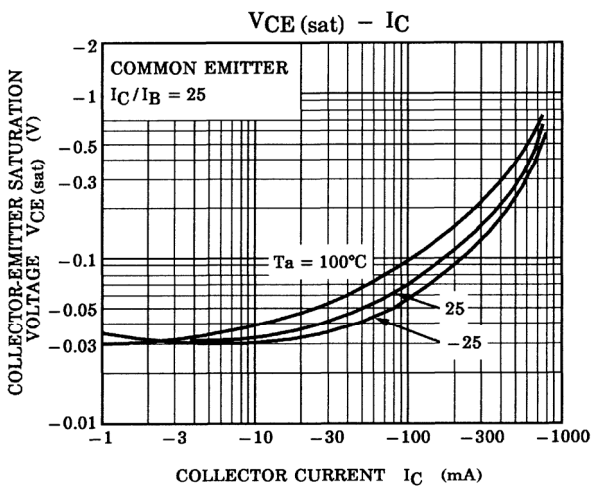
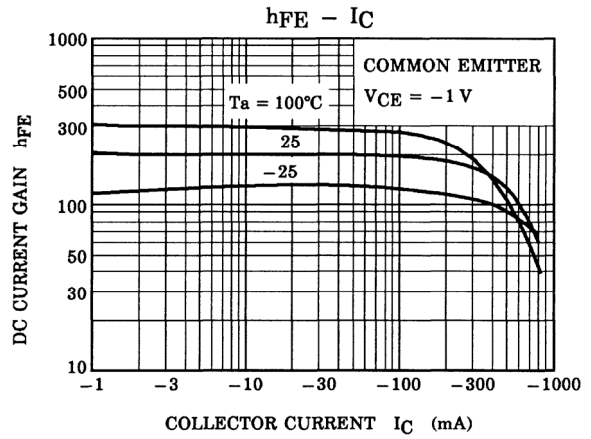
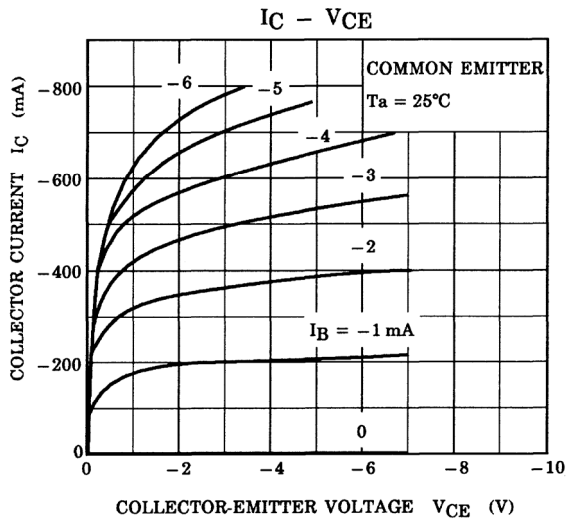


Weight: 0.012 g (typ.)

## Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	$I_{CBO}$	$V_{CB} = -30\text{ V}, I_E = 0$	—	—	-0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -50\text{ V}, I_C = 0$	—	—	-0.1	$\mu\text{A}$
Collector-emitter breakdown voltage	$V_{(BR) CEO}$	$I_C = -10\text{ mA}, I_B = 0$	-25	—	—	V
Emitter-base breakdown voltage	$V_{(BR) EBO}$	$I_E = -0.1\text{ mA}, I_C = 0$	-5	—	—	V
DC current gain	$h_{FE} (1)$ (Note)	$V_{CE} = -1\text{ V}, I_C = -100\text{ mA}$	100	—	320	
	$h_{FE} (2)$	$V_{CE} = -1\text{ V}, I_C = -800\text{ mA}$	40	—	—	
Collector-emitter saturation voltage	$V_{CE (sat)}$	$I_C = -500\text{ mA}, I_B = -20\text{ mA}$	—	—	-0.4	V
Base-emitter voltage	$V_{BE}$	$V_{CE} = -1\text{ V}, I_C = -10\text{ mA}$	-0.5	—	-0.8	V
Transition frequency	$f_T$	$V_{CE} = -5\text{ V}, I_C = -10\text{ mA}$	—	120	—	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	13	—	pF

Note:  $h_{FE} (1)$  classification O: 100~200, Y: 160~320



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20070701-EN GENERAL

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